NSN 5961-01-364-7864

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View Online at https://aerobasegroup.com/nsn/5961-01-364-7864 **Inclosure Material:** Metal **Overall Length:** Between 4.905 inches and 5.710 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: D0-205aa **Mounting Method:** Threaded stud **Features Provided:** Reverse polarity **Overall Width Across Flats:** Between 1.031 inches and 1.063 inches Thready Qty Per Inch (tpi): 24 **Thread Size:** 0.375 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1200.0 nonrepetitive peak reverse voltage and 1000.0 working peak reverse voltage **Current Rating Per Characteristic:** 100.00 amperes collector current, dc absolute and 1600.00 amperes collector current, dc preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator: Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud **Specification Data:** 81349-mil-prf-19500/246 government specification Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization:

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Mil-std (military Standard):

Mil-prf-19500 spec.